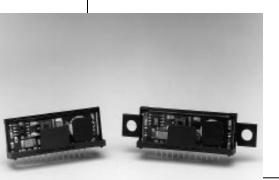
PT6305

Series

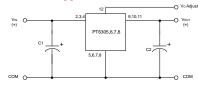
3 AMP HIGH-PERFORMANCE ADJUSTABLE ISR



- Single-Device 5V to 3V Power
- 85% Efficiency
- Small SIP Footprint: 0.36" x 2.00" x 0.60"(H)
- Wide Input Voltage Range: +4.5V to +9.0V
- Internal Short Circuit Protection
- Over-Temperature Protection

The PT6305N is Power Trends' new high performance +5V to +3.3V, 3 Amp, 12-Pin SIP (Single In-line-Package) Integrated Switching Regulator (ISR). This high-performance ISR allows easy integration of low-power 3.3V logic IC's into existing 5V systems without redesigning the central power supply. Only one external capacitor is required for proper operation. The PT6306,7,8 can be used to power high-speed data buses (+2.1V), or the new GTL (+1.2V) logic buses.

Standard Application



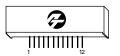
 C_1 = Optional electrolytic (100 μ F)

Pin-Out Information

Pin No.	Function
1	N/C
2	V_{in}
3	Vin
4	V _{in}
5	GND
6	GND

Pin No.	runction		
7	GND		
8	GND		
9	V _{out}		
10	V _{out}		
11	V _{out}		
12	Adjust		
	(See page 40.)		

Din No. Function



Ordering Information

 $PT6305 \square = +3.3 \text{ Volts}$

PT6306 □ = +1.8 Volts

 $PT6307 \square = +2.1 \text{ Volts}$

PT6308□ = +1.2 Volts

(For dimensions, see page 66.)

PT Series Suffix (PT1234X)

Case/Pin	Heat Tab Configuration		
Configuration	None	Side	
Vertical Through-Hole	N	R	
Horizontal Through-Hole	Α	G	
Horizontal Surface Mount	С	В	

(See Thermal Application Notes on page 44 for heat tab

Specifications

Characteristics			PT6305 SERIES			
(T _A =25°C unless noted) Symbols	Symbols	Conditions	Min	Тур	Max	Units
Output Current	I_{o}	$4.5 \le V_{in} \le V_{in} MAX$	0.3		3.0**	ADC
Current Limit	I_{cl}	$V_{in} = +5V$	_	3.6	5.0	ADC
Short Circuit Current	I_{sc}	$V_{in} = +5V$	_	5.0	_	Apk
Input Voltage Range	$ m V_{in}$	$\begin{array}{ccc} 0.3 \text{A} \leq \text{I}_{\text{o}} \leq 3.0 \text{A} & \text{PT}6305 \text{N} \\ \text{PT}6306 \text{N} & \text{PT}6307 \text{N} \\ \text{PT}6307 \text{N} & \text{PT}6308 \text{N} \end{array}$	4.5 4.5 4.5 4.5		9 9 9 6.0	VDC VDC VDC VDC
Static Voltage Tolerance	V_{o}	$\begin{array}{c} V_{in} = +5 V, I_o = 3.0 A & PT6305 N \\ 0 ^{\circ} C \leq T_a \leq +70 ^{\circ} C & PT6306 N \\ PT6306 N & PT6308 N \end{array}$	3.2 1.7 2.0 1.1	3.3 1.8 2.1 1.2	3.4 1.9 2.2 1.3	VDC VDC VDC VDC
Line Regulation	Reg _{line}	$4.5V \le V_{in} \le 5.5V, I_o = 3.0A$	_	±25	±50	mV
Load Regulation	Regload	$V_{in} = +5V, 0.3 \le I_o \le 3.0A$	_	±25	±50	mV
V _o Ripple/Noise pk-pk	V_n	$V_{in} = 5V, I_o = 3.0A$	_	66	_	mV
Transient Response with $C_2 = 100 \mu F$	$egin{array}{c} t_{ m tr} \ V_{ m os} \end{array}$	$I_{\rm o}$ step between 1.5A and 3.0A $V_{\rm o}$ over/undershoot	=	200 200	=	μSec mV
Efficiency η	V _{in} = +5V, I _o = 1.5A PT6305N PT6306N PT6307N PT6308N		85 74 77 63		% % %	
	V _{in} = +5V, I _o = 3.0A PT6305N PT6306N PT6307N PT6308N	_ _ _	80 68 72 57		% % %	
Switching Frequency	f _o	$4.5 \le V_{in} \le V_{in} MAX$ $0.3A \le I_o \le 3.0A$	500	650	800	KHz
Operating Temperature	T_a	Free Air Convection (40-60 LFM) Over V _{in and} I _o Ranges	0	_	+70*	°C
Thermal Resistance	θ_{ja}	Free Air Convection (40-60 LFM)	_	25	_	°C/W
Storage Temperature	T_s	_	-40	_	+125	°C
Mechanical Shock	Per Mil-STD- mounted to a	883D, Method 2002.3 Condition A, 1 msec, Half Sine, fixture	_	_	500	G's
Mechanical Vibration	Per Mil-STD	-883D, Method 2007.2 Condition A, 20-2000 Hz	_	_	15	G's
Weight	_	_	_	11.2	_	grams
Relative Humidity	_	Non-condensing	0		95	%

*See Thermal Derating chart. **The PT6305 Series can be easily paralleled to provide output current in multiples of 3 amps. Please contact a Power Trends' Application Engineer for the appropriate application note. Note: The PT6305 Series requires a 100µF electrolytic capacitor for proper operation in all applications.

C₂ = Required 100µF electrolytic (No tantalum) See capacitor application note on page 43.

High-Performance ISRs

CHARACTERISTIC DATA

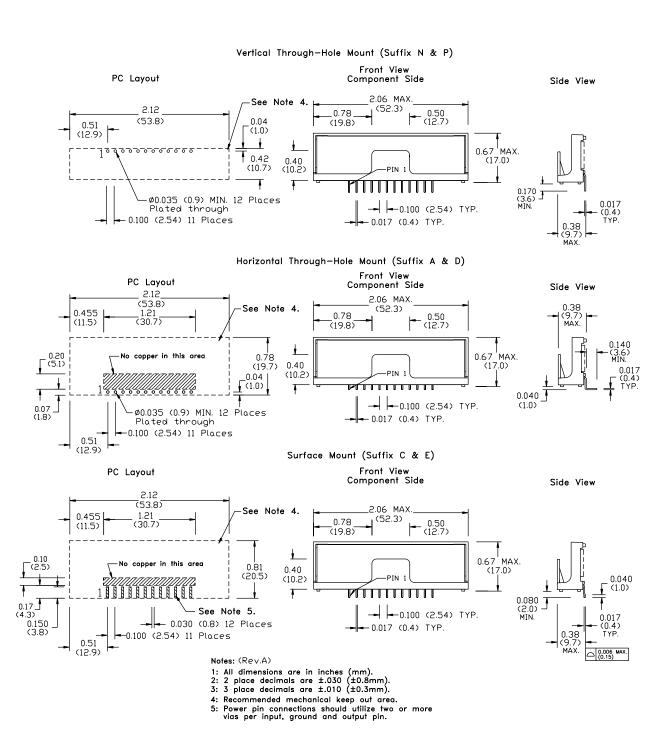
PT6305, 3.3 VDC PT6307, 2.1 VDC PT6308, 1.2 VDC (See Note 1) (See Note 1) (See Note 1) **Efficiency vs Output Current Efficiency vs Output Current Efficiency vs Output Current** 4:57 % % - - - · 4.5V Total Disease Efficiency. Efficiency 70 70 - - - 5.0V Efficiency 70 - - · 8.0V - - · 8.0V 60 - 9.0V 9.0V 50 1.5 lout-(Amps) 1.5 0.5 1.5 2 2.5 0.5 3 lout-(Amps) lout-(Amps) **Ripple vs Output Current Ripple vs Output Current Ripple vs Output Current** 100 100 - - 9.0V - - - 9.0V - - - · 6.0V (m (v) Ripple-(mV) --- 8.0V - - - 8.0\ 60 - - - 5.5V - - - 5.5V 20 20 0.5 2.5 1.5 1.5 1.5 2.5 lout-(Amps) **Minimum Input Voltage Minimum Input Voltage** (See Note 2) (See Note 2) **Minimum Input Voltage** (See Note 2) 4.5 4.5 4.5 4.3 4.25 4.25 4.1 Vin-(Volts) 3.9 3.75 3.7 0.5 15 2.5 0.5 15 2.5 0.5 1.5 2.5 Thermal Derating (Ta) Thermal Derating (T_a) Thermal Derating (Ta) (See Note 3) (See Note 3) (See Note 3) 2.5 2.5 2.5 lout-(Amps) 1.5 1.5 0.5 0.5 0.5 4.5 8.5 10.5 4.5 6.5 10.5 4.5 Vin-(Volts) Vin-(Volts) **Power Dissipation vs Output Current Power Dissipation vs Output Current Power Dissipation vs Output Current** 2.5 2.5 - - - 6.0V - 8.0V - · - 5.5V Pd-(Watts) 1.5 1.5 - 5.5V - - 5.5V - - · 5.0V - - - · 5.0V 4.5V - 4.5V 4.5V 0.5 0.5 2.5 0 1.5 0 0.5 1.5 2.5 1.5

Note 1: All data listed in the above graphs, except for derating data, has been developed from actual products tested at 25° C. This data is considered typical data for the ISR. Note 2: Minimum V_m data is typical and is not guaranteed. The data corresponds to a 2% output voltage drop. Note 3: Thermal derating graphs are developed in free air convection cooling of 40-60 LFM with no optional heat tab soldered in a printed circuit board. (See Thermal Application Notes).



PACKAGE INFORMATION AND DIMENSIONS

Revised 2/11/2000



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